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Publication Order Number: NTST20100CT/D

NTST20100CTG, NTSB20100CT-1G, NTSJ20100CTG, NTSB20100CTG

Trench-based Dual Schottky Rectifier, Very Low Forward Voltage, 20A, 100V

Features

- Fine Lithography Trench–based Schottky Technology for Very Low Forward Voltage and Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- Low Thermal Resistance
- High Surge Capability
- These are Pb–Free Devices

Typical Applications

- Switching Power Supplies including Notebook / Netbook Adapters, ATX and Flat Panel Display
- High Frequency and DC–DC Converters
- Freewheeling and OR-ing diodes
- Reverse Battery Protection
- Instrumentation

Mechanical Characteristics

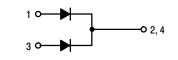
- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94-0 @ 0.125 in
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Maximum for 10 sec

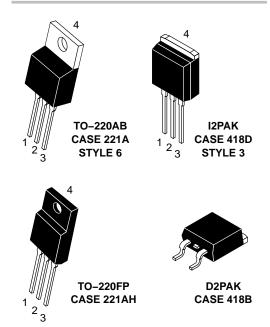


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PIN CONNECTIONS





ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} V _{RWM} V _R	100	V
Average Rectified Forward Current (Rated V_R , $T_C = 130^{\circ}C$)	Per device Per diode	I _{F(AV)}	20 10	A
Peak Repetitive Forward Current (Rated V_R , Square Wave, 20 kHz, T_C = 125°C)	Per device Per diode	I _{FRM}	40 20	A
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)		I _{FSM}	150	A
Operating Junction Temperature		TJ	-40 to +150	°C
Storage Temperature		T _{stg}	-40 to +150	°C
Voltage Rate of Change (Rated V _R)		dv/dt	10,000	V/µs

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

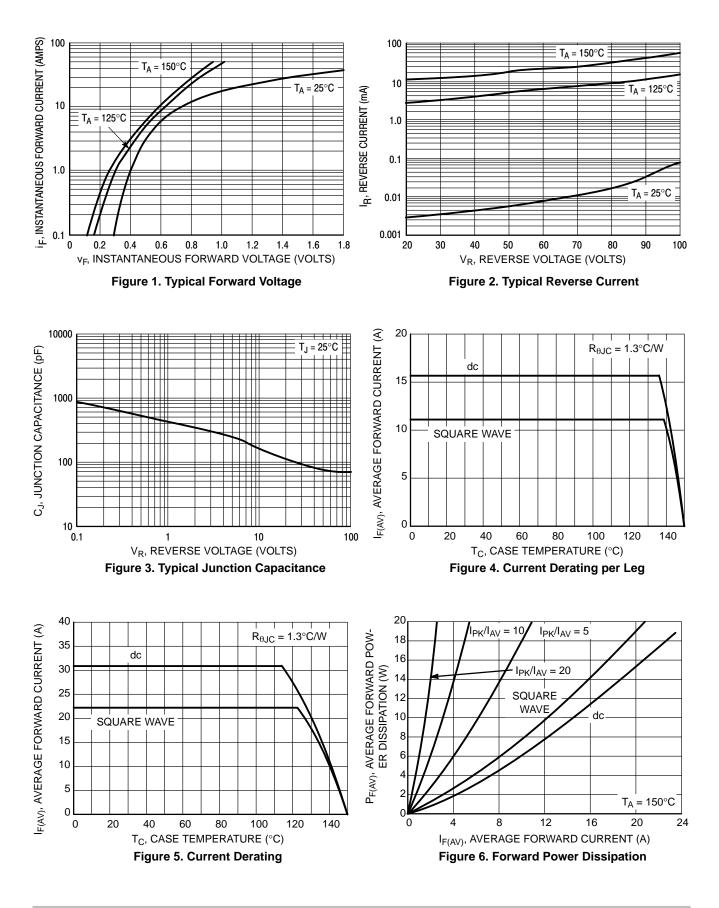
Rating	Symbol	NTST20100CTG, NTSB20100CT-1G	NTSB20100CTG	NTSJ20100CTG	Unit
Maximum Thermal Resistance per Diode Junction-to-Case Junction-to-Ambient	$R_{ heta JC} \ R_{ heta JA}$	2.5 70	1.5 46.9	4.49 105	°C/W °C/W

ELECTRICAL CHARACTERISTICS (Per Leg unless otherwise noted)

Rating	Symbol	Тур	Max	Unit
Maximum Instantaneous Forward Voltage (Note 1)	۷ _F			V
$(I_F = 5 \text{ A}, T_J = 25^{\circ}\text{C})$		0.55	_	
$(I_F = 10 \text{ A}, T_J = 25^{\circ}\text{C})$		0.65	0.83	
$(I_F = 5 \text{ A}, T_J = 125^{\circ}\text{C})$ $(I_F = 10 \text{ A}, T_J = 125^{\circ}\text{C})$		0.50 0.58	_ 0.68	
Maximum Instantaneous Reverse Current (Note 1)	I _R			
$(V_R = 70 \text{ V}, \text{ T}_J = 25^{\circ}\text{C})$		17	-	μΑ
(V _R = 70 V, T _J = 125°C)		5.3	-	mA
(Rated dc Voltage, $T_J = 25^{\circ}C$) (Rated dc Voltage, $T_J = 125^{\circ}C$)		_ 12	800 25	μA mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width = 300 μ s, Duty Cycle $\leq 2.0\%$



TYPICAL CHARACTERISITICS

TYPICAL CHARACTERISITICS

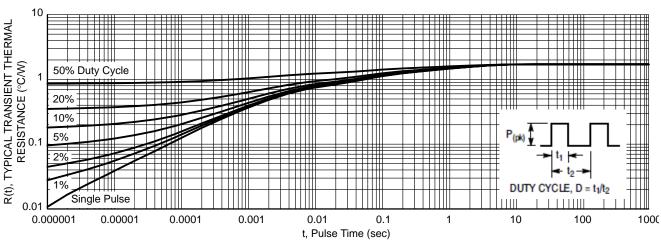
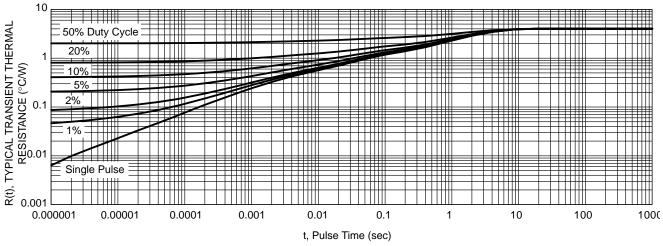
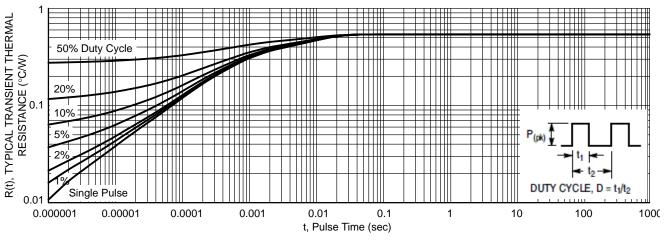


Figure 7. Typical Transient Thermal Response, Junction-to-Case for NTST20100CT and NTSB20100CT-1G









ORDERING INFORMATION

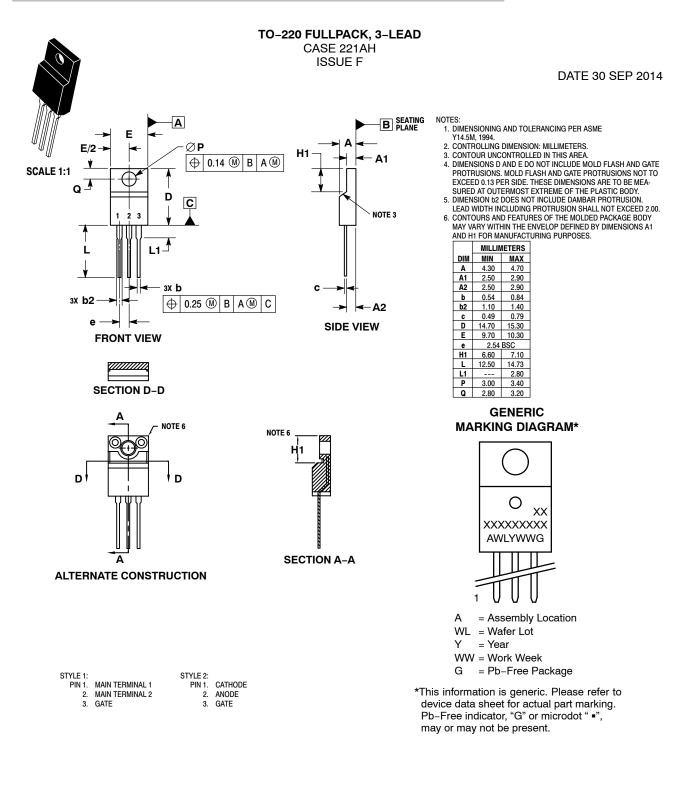
Device	Package	Shipping
NTST20100CTG	TO-220AB (Pb-Free)	50 Units / Rail
NTSB20100CT-1G	I ² PAK 50 Units / Rail (Pb–Free)	
NTSJ20100CTG	TO-220FP (Halide-Free)	50 Units / Rail
NTSB20100CTG	D ² PAK (Pb–Free)	50 Units / Rail
NTSB20100CTT4G	D ² PAK (Pb–Free)	800 / Tape & Reel

AYWW AYWW TS20100CG AYWW AYWW TS20100CG TS2100Cx TS20100CG AKA AKA AKA AKA 1 $\overline{1}$ TO-220FP I²PAK D²PAK TO-220AB

MARKING DIAGRAMS

- A = Assembly Location
- Y = Year
- WW = Work Week
- AKA = Polarity Designator
- x = G or H
- G = Pb–Free Package
- H = Halide–Free Package

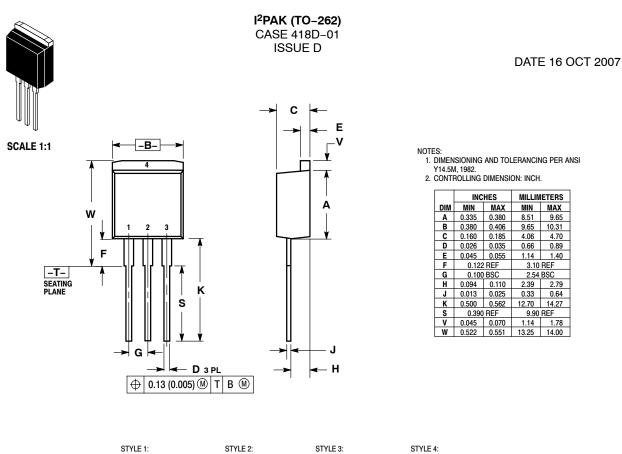




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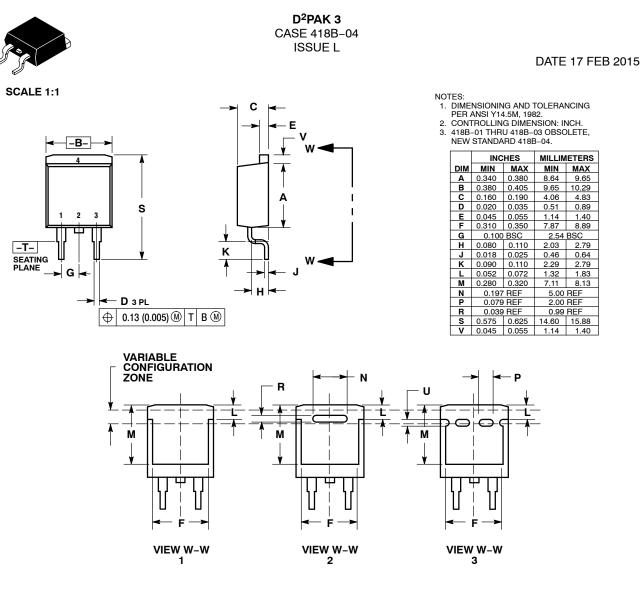


STYLE 1:		STYLE 2:		STYLE 3:		STYLE 4:	
PIN 1.	BASE	PIN 1.	GATE	PIN 1.	ANODE	PIN 1.	GATE
2.	COLLECTOR	2.	DRAIN	2.	CATHODE	2.	COLLECTOR
3.	EMITTER	3.	SOURCE	3.	ANODE	3.	EMITTER
4.	COLLECTOR	4.	DRAIN	4.	CATHODE	4.	COLLECTOR

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STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:	STYLE 6:
PIN 1. BASE	PIN 1. GATE	PIN 1. ANODE	PIN 1. GATE	PIN 1. CATHODE	PIN 1. NO CONNECT
2. COLLECTOR	2. DRAIN	2. CATHODE	2. COLLECTOR	2. ANODE	2. CATHODE
3. EMITTER	SOURCE	ANODE	3. EMITTER	CATHODE	3. ANODE
4. COLLECTOR	4. DRAIN	4. CATHODE	4. COLLECTOR	4. ANODE	4. CATHODE

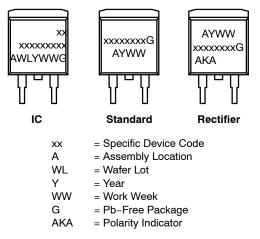
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D²PAK 3 CASE 418B-04 ISSUE L

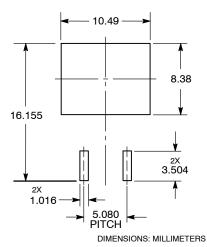
DATE 17 FEB 2015

GENERIC MARKING DIAGRAM*



*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present.

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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